

PS2703-1

HIGH ISOLATION VOLTAGE
HIGH COLLECTOR TO EMITTER VOLTAGE TYPE
SOP MULTI PHOTOCOUPLER SERIES

R08DS0098EJ0300
Rev.3.00
Jan 29, 2013

DESCRIPTION

The PS2703-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

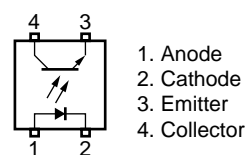
This is mounted in a plastic SOP (Small Outline Package) for high density applications.

This package has shield effect to cut off ambient light.

FEATURES

- High isolation voltage ($BV = 3\,750\text{ V r.m.s.}$)
- High collector to emitter voltage ($V_{CE0} = 120\text{ V}$)
- SOP (Small Outline Package) type
- Each isolated channel per package
- High-speed switching ($t_r, t_f = 10\text{ }\mu\text{s TYP.}$)
- <R> • Taping product number: PS2703-1-F3
- <R> • Safety standards
 - UL approved: No. E72422
 - BSI approved (BS EN 60065, BS EN 60950)
 - CSA approved: No. CA 101391(CA5A, CAN/CSA-C22.2 60065, 60950)
 - DIN EN 60747-5-5 (VDE 0884-5) approved (Option)

PIN CONNECTION (Top View)



- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

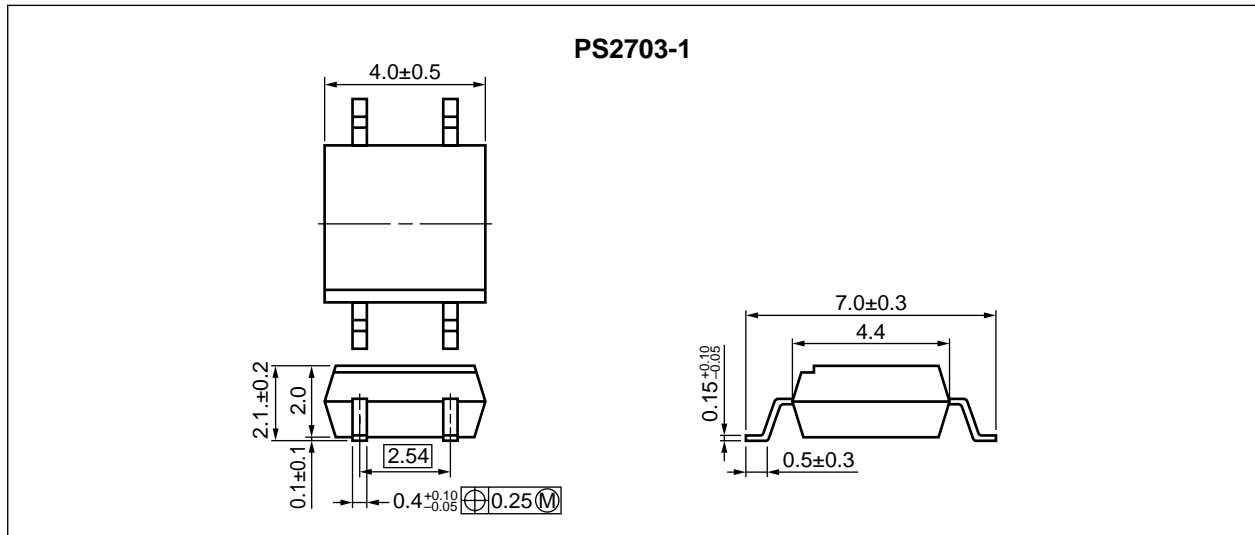
APPLICATIONS

- Hybrid IC
- Telephone/FAX
- FA/OA equipment
- Programmable logic controllers
- Power supply

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

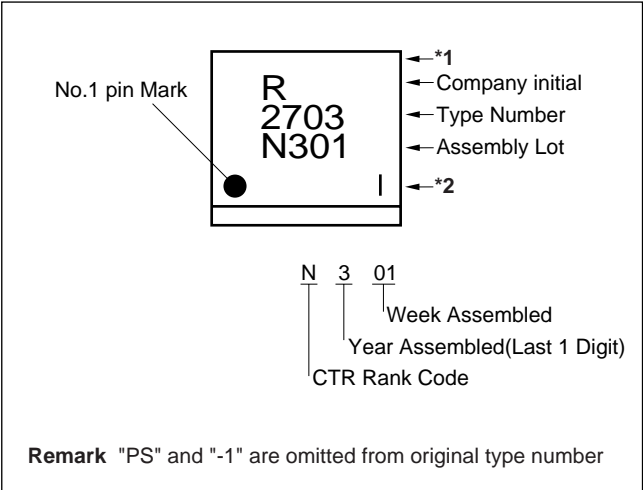
PACKAGE DIMENSIONS (UNIT: mm)



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	5 mm
Outer Creepage Distance	5 mm
Inner Creepage Distance	2.5 mm
Isolation Thickness	0.3 mm

<R> MARKING EXAMPLE



Note: Bar indication contents of *1 and *2

<p>Made in Taiwan</p> <p>(*1: No indication *2: No indication)</p>	<p>The diagram shows a square marking area with a black dot in the bottom-left corner. Inside the square, the text "R 2703 N301" is printed. A vertical bar " " is shown to the right of the square with an arrow pointing to it labeled "*2".</p>
<p>Made in Japan</p> <p>(*1: No indication *2: " " (Vertical bar))</p>	<p>The diagram shows a square marking area with a black dot in the bottom-left corner. Inside the square, the text "R 2703 N301" is printed. A vertical bar " " is shown to the right of the square with an arrow pointing to it labeled "*2". Below the square, the text "N 3 01" is shown with arrows pointing to "N" (labeled "CTR Rank Code"), "3" (labeled "Year Assembled (Last 1 Digit)"), and "01" (labeled "Week Assembled"). A vertical bar " " is shown to the right of "01" with an arrow pointing to it labeled "*2".</p>

<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS2703-1-F3	PS2703-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products (UL, BSI, CSA approved)	PS2703-1
PS2703-1-V-F3	PS2703-1-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5 (VDE 0884-5) Approved (Option)	

Note: ^{*1}. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I _F	50	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation Derating	ΔP _D /°C	0.8	mW/°C
	Power Dissipation	P _D	80	mW
	Peak Forward Current ^{*1}	I _{FP}	1	A
Transistor	Collector to Emitter Voltage	V _{CEO}	120	V
	Emitter to Collector Voltage	V _{ECO}	6	V
	Collector Current	I _C	30	mA
	Power Dissipation Derating	ΔP _D /°C	1.5	mW/°C
	Power Dissipation	P _C	150	mW
Isolation Voltage ^{*2}		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T _A	–55 to +100	°C
Storage Temperature		T _{stg}	–55 to +150	°C

Notes: ^{*1}. PW = 100 μs, Duty Cycle = 1%

^{*2}. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.
Pins 1-2 shorted together, 3-4 shorted together.

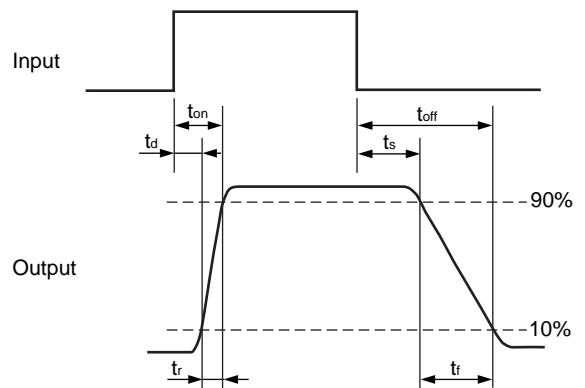
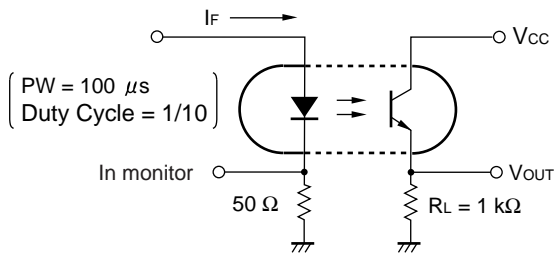
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

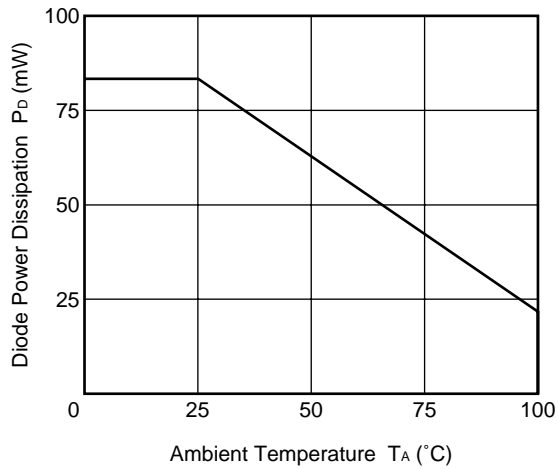
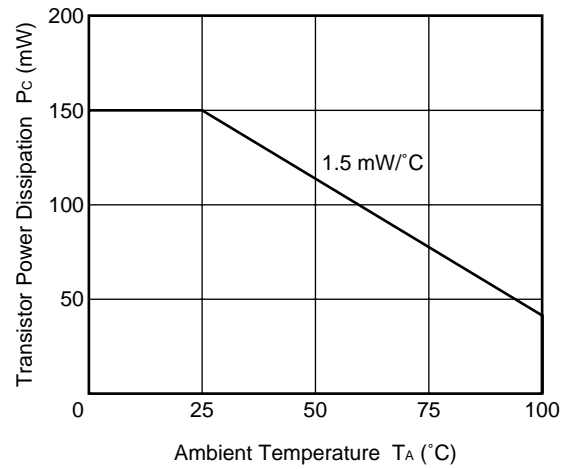
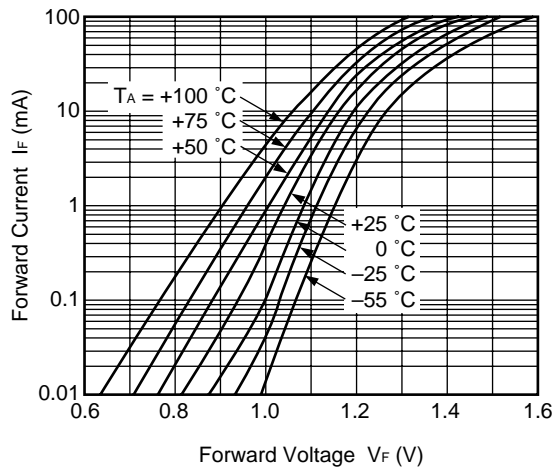
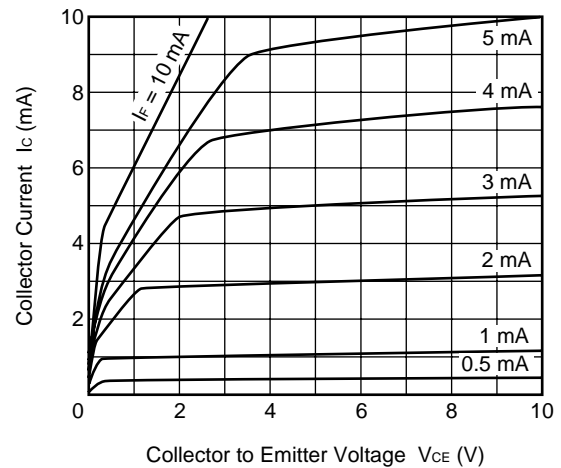
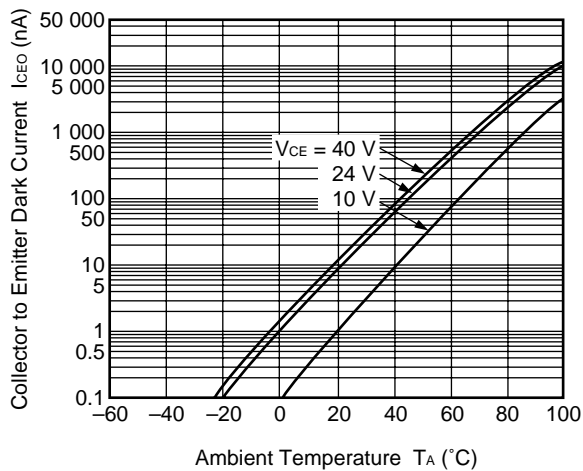
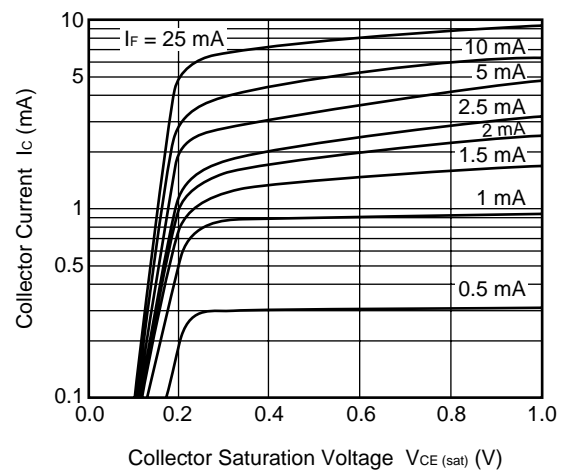
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 5 mA		1.1	1.4	V
	Reverse Current	I _R	V _R = 5 V			5	μA
	Terminal Capacitance	C _t	V = 0 V, f = 1 MHz		30		pF
Transistor	Collector to Emitter Dark Current	I _{CEO}	I _F = 0 mA, V _{CE} = 120 V			100	nA
Coupled	Current Transfer Ratio (I _C /I _F) ^{*1}	CTR	I _F = 5 mA, V _{CE} = 5 V	50	150	400	%
			I _F = 1 mA, V _{CE} = 5 V	10	80		
	Collector Saturation Voltage	V _{CE(sat)}	I _F = 10 mA, I _C = 2 mA			0.3	V
	Isolation Resistance	R _{I-O}	V _{I-O} = 1 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time ^{*2}	t _r	V _{CC} = 5 V, I _C = 2 mA, R _L = 1 kΩ		10		μs
	Fall Time ^{*2}	t _f			10		
	Turn-on Time ^{*2}	t _{on}			13		
	Turn-off Time ^{*2}	t _{off}			11		

Notes: ^{*1} 1. CTR rank

CTR rank	CTR (%)	Conditions
K	200 to 400	I _F = 5 mA, V _{CE} = 5 V
	80 and larger	I _F = 1 mA, V _{CE} = 5 V
L	100 to 300	I _F = 5 mA, V _{CE} = 5 V
	25 and larger	I _F = 1 mA, V _{CE} = 5 V
M	50 to 150	I _F = 5 mA, V _{CE} = 5 V
	10 and larger	I _F = 1 mA, V _{CE} = 5 V

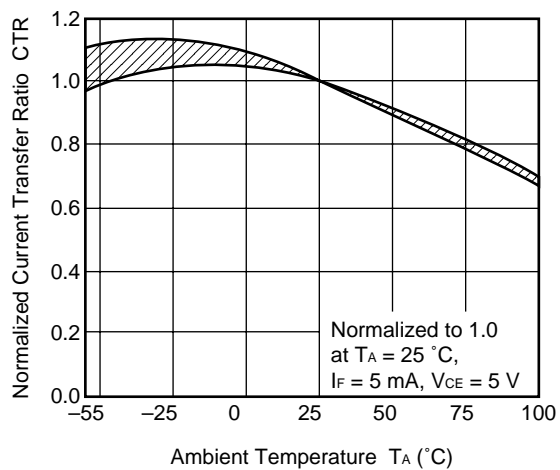
^{*2} 2. Test circuit for switching time



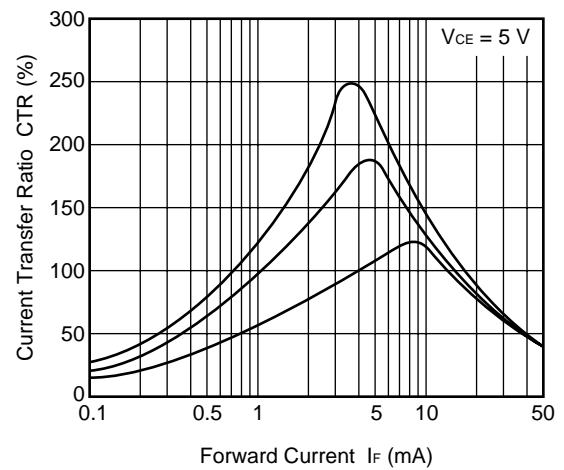
<R> **TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)****DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE****TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE****FORWARD CURRENT vs. FORWARD VOLTAGE****COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE****COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE****COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE**

Remark The graphs indicate nominal characteristics.

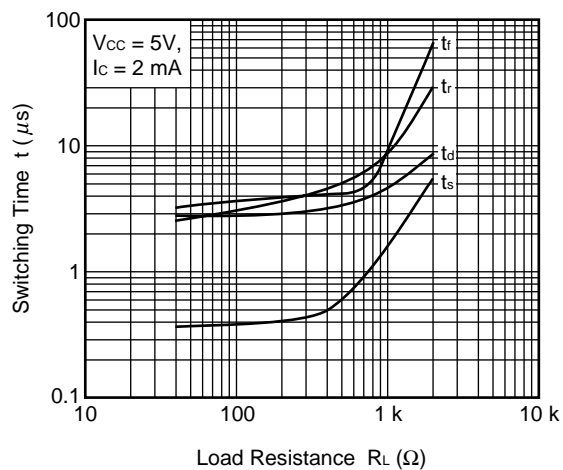
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



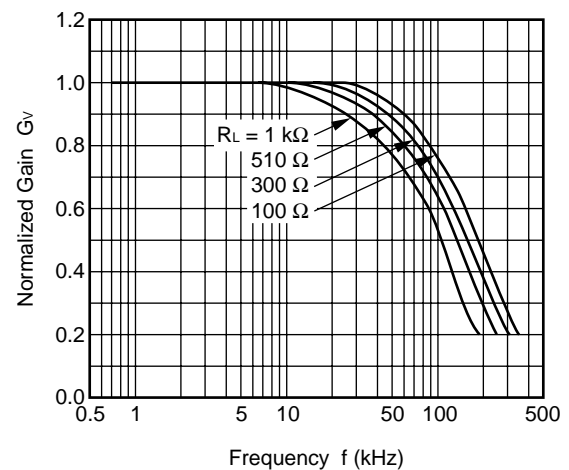
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



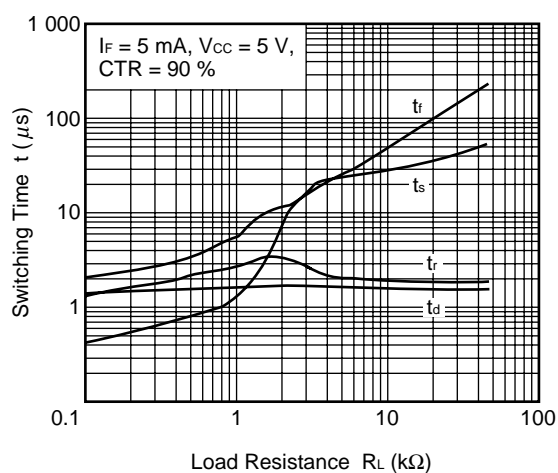
SWITCHING TIME vs. LOAD RESISTANCE



FREQUENCY RESPONSE



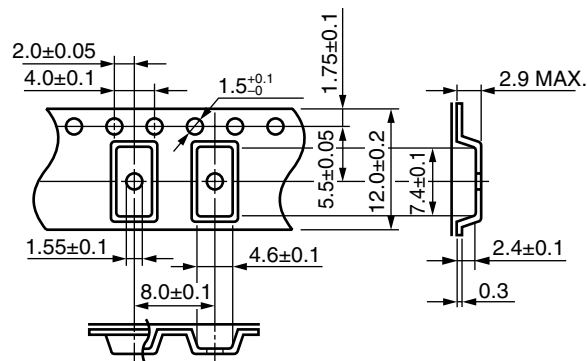
SWITCHING TIME vs. LOAD RESISTANCE



Remark The graphs indicate nominal characteristics.

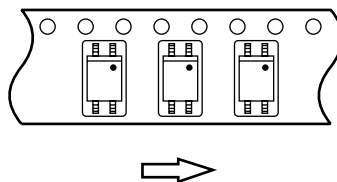
<R> TAPING SPECIFICATIONS (UNIT: mm)

Outline and Dimensions (Tape)

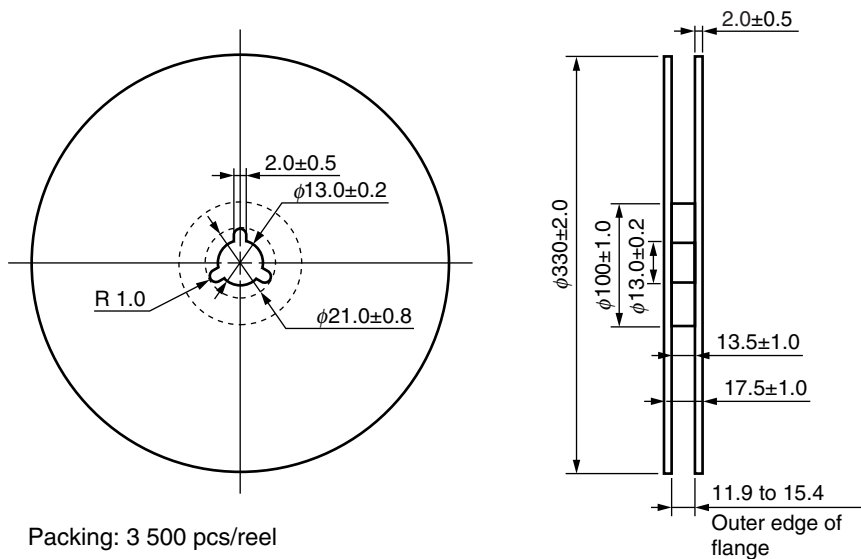


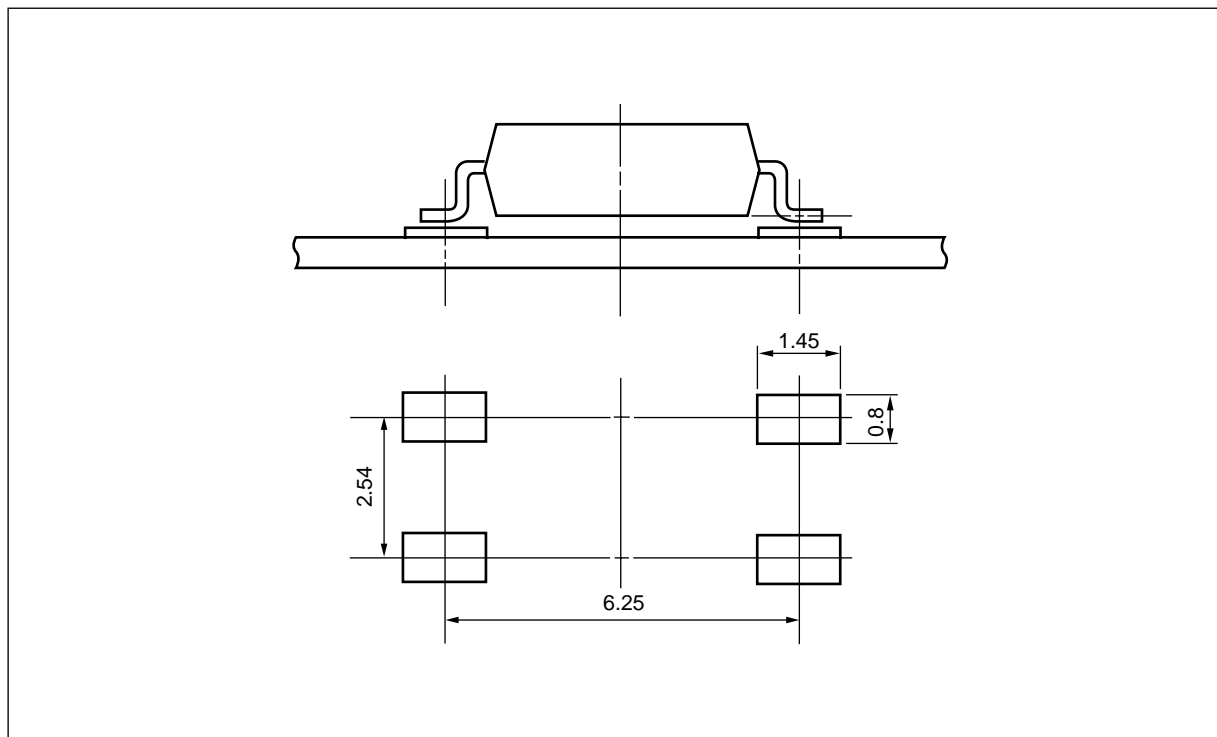
Tape Direction

PS2703-1-F3



Outline and Dimensions (Reel)



<R> **RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)**

Remark All dimensions in this figure must be evaluated before use.

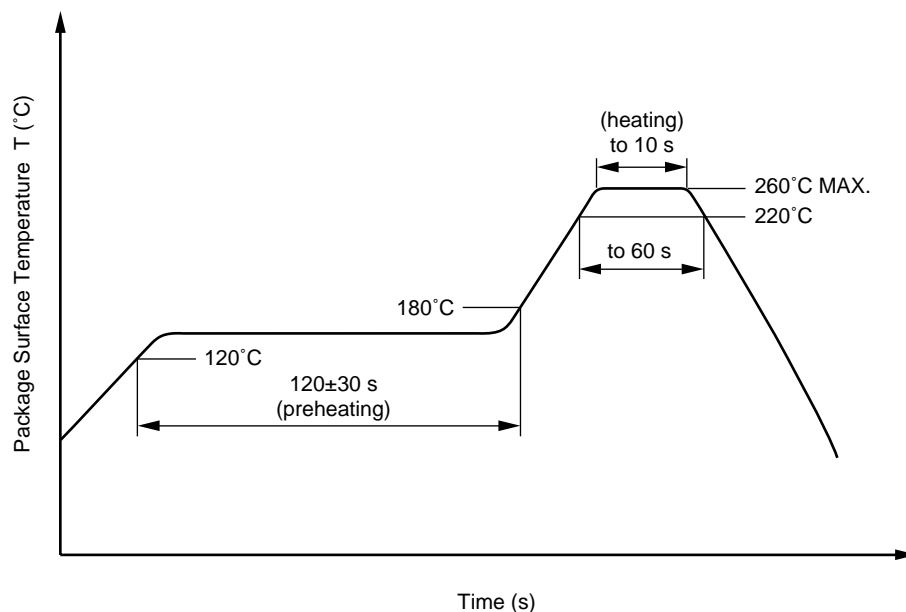
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- | | |
|---|--|
| • Peak reflow temperature | 260°C or below (package surface temperature) |
| • Time of peak reflow temperature | 10 seconds or less |
| • Time of temperature higher than 220°C | 60 seconds or less |
| • Time to preheat temperature from 120 to 180°C | 120±30 s |
| • Number of reflows | Three |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- | | |
|-------------------------|--|
| • Temperature | 260°C or below (molten solder temperature) |
| • Time | 10 seconds or less |
| • Preheating conditions | 120°C or below (package surface temperature) |
| • Number of times | One (Allowed to be dipped in solder including plastic mold portion.) |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(3) Soldering by Soldering Iron

- | | |
|--|--|
| • Peak Temperature (lead part temperature) | 350°C or below |
| • Time (each pins) | 3 seconds or less |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

<R>

(4) Cautions

- | | |
|----------|--|
| • Fluxes | Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent. |
|----------|--|

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{IORM} U_{pr}	707 1131	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{pr}	1 325	V_{peak}
Highest permissible overvoltage	U_{TR}	6 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	T_{stg}	–55 to +150	°C
Operating temperature range	T_A	–55 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^\circ\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^\circ\text{C}$	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $P_{si} = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = T_{si}$	T_{si} I_{si} P_{si} Ris MIN.	150 300 500 10^9	°C mA mW Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Revision History	PS2703-1 Data Sheet
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Rev.	Date	Description	
		Page	Summary
1.00	Mar 31, 2003	–	This data sheet was released as PN10242EJ01V0DS
3.00	Jan 29, 2013	Throughout	Renesas format is applied to this data sheet.
		p.1	The ordering number and safety standards are revised.
		p.2	PHOTOCOUPLER CONSTRUCTION is added.
		p.3	The explanation in MARKING EXAMPLE is revised. One of the captions in MARKING EXAMPLE is revised from Trade Mark to Company initial.
		p.4	ORDERING INFORMATION is modified with the revision of the safety standards.
		p.5	Turn-on Time (t_{on}) and Turn-off Time (t_{off}) are added to the table in ELECTRICAL CHARACTERISTICS.
		p.5	The timing chart is added in the note *2.
		p.7	The graph of LONG TERM CTR DEGRADATION is deleted from those in TYPICAL CHARACTERISTICS.
		p.8	PS2703-1-F4 is deleted from Tape Direction image in TAPING SPECIFICATIONS.
		p.9	RECOMMENDED MOUNT PAD DIMENSIONS is added.
		p.10	The note about temperature condition of the recommended soldering conditions is deleted.
		p.12	The format of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT is revised. The value of maximum operating isolation voltage is changed to 707. The value of test voltage (partial discharge test, procedure a for type test and random test) is changed to 1130. The value of test voltage (partial discharge test, procedure b for all devices) is changed to 1325. The value of Current (input current I_F , $\Psi_i = 0$) is changed to 300. The value of Power (output or total power dissipation) is changed to 500.

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